-18V,-50A P-CHANNEL POWER MOSFET

Description

The SFN2005PT use advanced trench technology and design to provide excellent RDS(on) with low g

Features

Applications

Ordering Information

Part No.	Package	Marking	Material	Packing
SFN2005PT	PDFN3*3	SFN2005PT	Pb Free	Reel

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Electrical Characteristics

Characteristics	Sym
Off Chara	

Source-drain diode ratings and characteristics

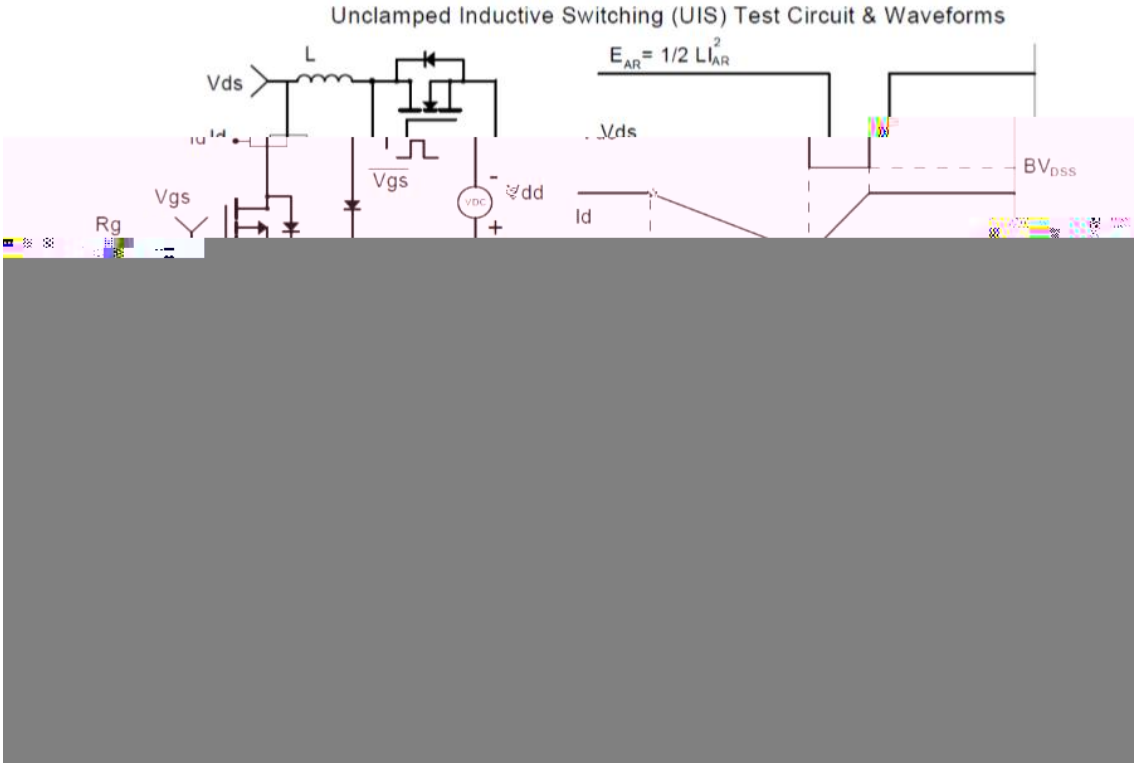
Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Continuous Source Current	I_S	Integral Reverse P-N Junction				

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Test Circuit





Package dimensions of PDFN3*3

Symbol	Min	Typ	Max
A	0.72		